

# WLSC

## Wire-bondable vertical Low-profile Si Capacitors down to 100 $\mu\text{m}$



Rev 2.2

### Key features

- Ultra low profile 100  $\mu\text{m}$ .
- Low leakage current.
- High stability (temperature and voltage).
- Negligible capacitance loss through aging.
- Compatible with standard wire bonding assembly (ball and wedge).

(please refer to our Assembly Application Note for more details)

### Key applications

- Any demanding applications such as radar, wireless infrastructure communication, data broadcasting...
- Standard wire bonding approach (top & bottom gold metallization), thanks to a perfect pad flatness.
- Decoupling / DC noise and harmonic filtering / Matching networks (e.g: GaN power amplifier, LDMOS).
- High reliability applications.
- Downsizing. Low profile applications (100  $\mu\text{m}$ ).
- Fully compatible with single layer ceramic capacitors and Metal Oxide Semiconductor.

The WLSC (100  $\mu\text{m}$  thick) capacitors target **RF High Power applications** for wireless communication (e.g: 5G), radar and data broadcasting systems. The WLSC capacitors are suitable for **DC decoupling, matching network, and harmonic / noise filtering functions**. The unique technology of integrated passive devices in silicon developed by Murata Integrated Passive Solutions, can **solve most of the problems encountered** in demanding applications. These Si capacitors in ultra-deep trenches have been developed with a semiconductor process which enables the integration of **high capacitance density** from 1.55 nF/mm<sup>2</sup> to 250 nF/mm<sup>2</sup> (with a breakdown voltage of respectively **450 V** to 11 V).

Our SiCap technology features **high reliability** - up to 10 times better than alternative capacitors technologies - thanks to a full control of the production process with **high temperature curing** (above 900°C) generating a highly pure oxide. This technology provides **industry-leading performance** particularly in terms of capacitor stability over the full operating DC voltage & temperature range. In addition, intrinsic properties of the silicon show a low dielectric absorption and a low to zero piezo electric effect resulting **in no memory effect**. This Silicon based technology is ROHS compliant.



## Electrical specifications

WLSC.xxx	Wire-Bondable vertical Low-profile Si Capacitors down to 100 μm from -55°C to 150°C			
Part number	Capacitance	BV	Case size	Thickness
935146528247-xxT	47 pF	150 V	0201	100 μm
935146522310-xxT	100 pF	150 V	0101	100 μm
935146521310-xxT	100 pF	150 V	0202	100 μm
935146529315-xxT	150 pF	150 V	015015	100 μm
935146832410-xxT	1 nF	30 V	0101	100 μm
935146632410-xxT	1 nF	50 V	0101+	100 μm
935146521410-xxT	1 nF	150 V	0202	100 μm
935146831510-xxT	10 nF	30 V	0202	100 μm
935146630510-xxT	10 nF	50 V	0303	100 μm
935146634522-xxT	22 nF	50 V	0504	100 μm

Parameter	Value
Capacitance range	47 pF to 22 nF(*)
Capacitance tolerances	±15 % (*)
Operating temperature range	-55 °C to 150°C (*)
Storage temperature range	-70°C to 165°C(**)
Temperature coefficient	+60 ppm/K
Breakdown Voltage (BV)	11 V, 30 V, 50 V, 100 V, 150 V, 450 V(*)
Capacitance variation versus RVDC	0.02 %/V (from 0 to RVDC)
Equivalent Series Inductance (ESL)	Typ 50 pH @ SRF (***)
Equivalent Series Resistance (ESR)	Max 50 mΩ (***)
Insulation resistance	10 GΩ @ RVDC @ 25°C t>120s for 10 nF
Aging	Negligible, < 0.001 % / 1000 h
Reliability	FIT<0.017 parts / billions hours
Capacitor thickness	100 μm(*)

(\*) Other values on request (\*\*) w/o packing (\*\*\*) with wire-bonding de-embedded

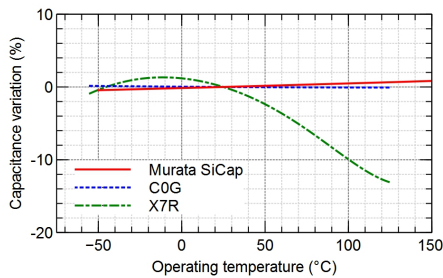


Fig. 1: Capacitance variation vs temperature (for WLSC and MLCC technologies)

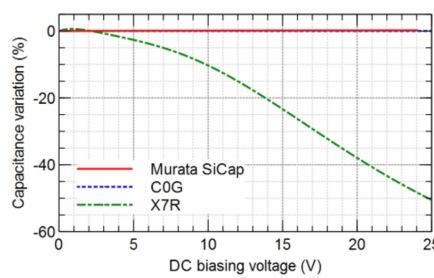


Fig.2: Capacitance variation vs DC biasing voltage @ BV30 (for WLSC and MLCC technologies)

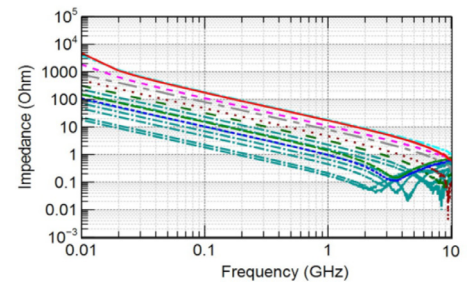
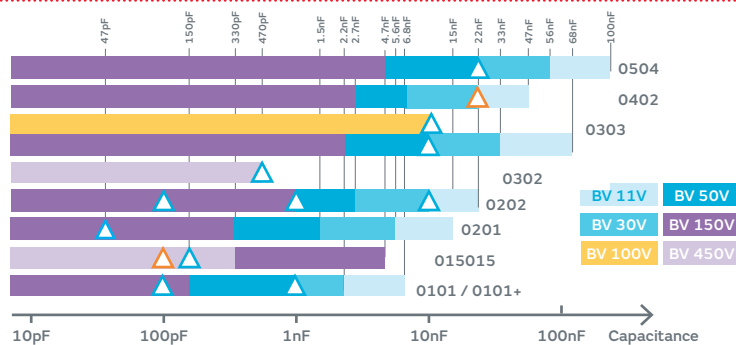


Fig.3: Various WLSC measurement results (Impedance in shunt mode) with capacitance value from 47pF to 1nF

## Capacitance range



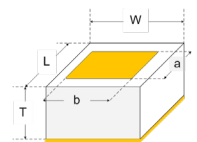
▲ Available parts.  
For other values, contact your Murata sales representative.  
▲ Under development.  
0101+ available as 1 nF-BV50 only.

## Termination

Can be directly mounted on the PCB using die bonding and wire bonding(s). Bottom electrode in Ti/Ni/Au and top electrode in Gold (TiWAu). Other top finishings available on request (ex: Aluminum). Compatible with standard wire bonding assembly (ball and wedge).

## Package Outline

	Pad dimension mm		Case size mm (typ ±0.02 mm)		
	a	b	L	W	T
0101	>0.15	>0.15	0.25	0.25	0.10
0101+	>0.15	>0.15	0.294(*)	0.294(*)	
015015	>0.281	>0.281	0.381	0.381	
0201	>0.40	>0.15	0.50	0.25	
0202	>0.40	>0.40	0.50	0.50	
0302	>0.7	>0.4	0.8	0.5	
0303	>0.70	>0.70	0.80	0.80	
0402	>0.9	>0.4	1.00	0.50	
0504	>1.15	>0.9	1.25	1.00	



(\*) Only for 1nF / BV50 case size = 0.294x0.294mm



**Packaging**

Tape & reel (up to 0202 case size included), waffle pack, film frame carrier or raw wafer delivery.

**Assembly by Soldering**

The attachment techniques recommended by Murata for the WLSC capacitors on the customers substrates are fully detailed in specific documents available on our website. To assure the correct use and proper functioning of Murata Silicon capacitors **please download the assembly instructions on [www.murata.com](http://www.murata.com) and read them carefully.**



**Please download the assembly instructions on [www.murata.com](http://www.murata.com) and read them carefully before use.**  
**在使用MURATA电容之前请从 [www.murata.com](http://www.murata.com) 网站上下载电容安装说明并仔细阅读**

For the assembly instructions, please go to : <https://www.murata.com/> and follow the sections : Products > Capacitor > Silicon Capacitor > WLSC Series

**Download the pdf files called “Assembly Note WBSC / WTSC / WXSC / WLSC\_V1.8\_Murata ”**

Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent or other industrial or intellectual property rights.

 [www.murata.com](http://www.murata.com)  
 [mis@murata.com](mailto:mis@murata.com)

# Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[Murata:](#)

[935146521310](#) [935146521410](#) [935146522310](#) [935146528247](#) [935146529315](#) [935146632410](#) [935146831510](#)  
[935146832410](#)